

# PN2222A NPN General-Purpose Amplifier

# Features

• This device is for use as a medium power amplifier and switch requiring collector currents up to 500mA.



# **Ordering Information**

Part Number	Top Mark	Package	Packing Method
PN2222ABU	PN2222A	TO-92 3L	Bulk
PN2222ATA	PN2222A	TO-92 3L	Ammo
PN2222ATF	PN2222A	TO-92 3L	Tape and Reel
PN2222ATFR	PN2222A	TO-92 3L	Tape and Reel

## Absolute Maximum Ratings<sup>(1), (2)</sup>

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at  $T_A = 25^{\circ}$ C unless otherwise noted.

Symbol	Parameter	Value	Unit
V <sub>CEO</sub>	Collector-Emitter Voltage	40	V
V <sub>CBO</sub>	Collector-Base Voltage	75	V
V <sub>EBO</sub>	Emitter-Base Voltage	6.0	V
۱ <sub>C</sub>	Collector Current	1.0	Α
T <sub>STG</sub>	Operating and Storage Junction Temperature Range	-55 to 150	°C

## Note:

- 1. These rating are based on a maximum junction temperature of 150  $^\circ\text{C}.$
- 2. These are steady-state limits. Fairchild Semiconductor should be consulted on applications involving pulsed or low-duty-cycle operation.

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# Thermal Characteristics<sup>(3)</sup>

Values are at  $T_A = 25^{\circ}C$  unless otherwise noted.

Symbol	Parameter	Max.	Unit
Б	Total Device Dissipation	625	mW
PD	Derate Above 25°C	5.0	mW/°C
R <sub>θJC</sub>	Thermal Resistance, Junction to Case	83.3	°C/W
R <sub>θJA</sub>	Thermal Resistance, Junction to Ambient	200	°C/W

### Note:

3. PCB size: FR-4, 76 mm x 114 mm x 1.57 mm (3.0 inch x 4.5 inch x 0.062 inch) with minimum land pattern size.

PN2222A — NPN General-Purpose Amplifier

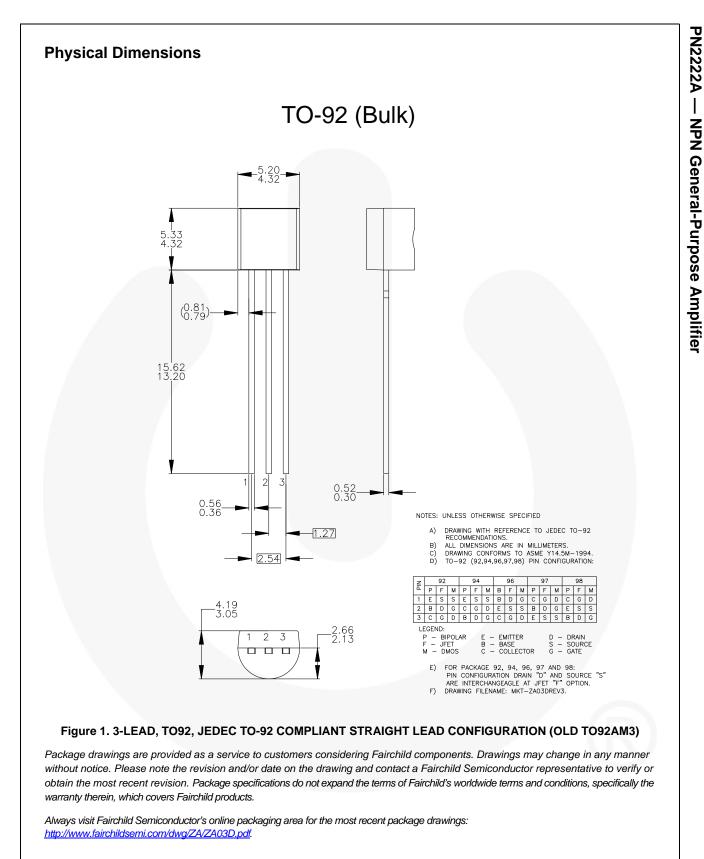
# **Electrical Characteristics**

Values are at  $T_A = 25^{\circ}C$  unless otherwise noted.

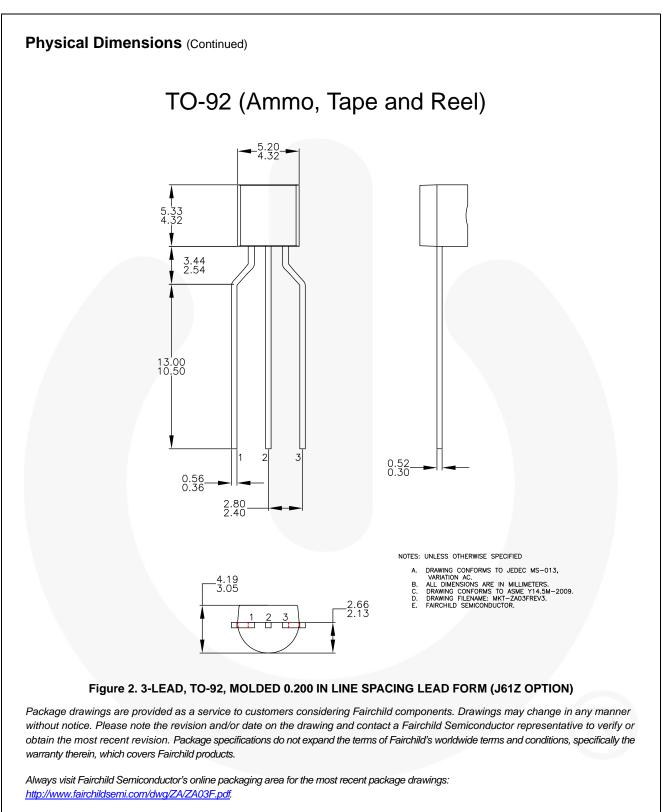
Symbol	Parameter	Conditions	Min.	Max.	Uni
Off Charact	eristics	•			
BV <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage <sup>(4)</sup>	I <sub>C</sub> = 10 mA, I <sub>B</sub> = 0	40		V
BV <sub>(BR)CBO</sub>	Collector-Base Breakdown Voltage	I <sub>C</sub> = 10 μA, I <sub>E</sub> = 0	75		V
BV <sub>(BR)EBO</sub>	Emitter-Base Breakdown Voltage	$I_{E} = 10 \ \mu A, \ I_{C} = 0$	6.0		V
I <sub>CEX</sub>	Collector Cut-Off Current	$V_{CE} = 60 \text{ V}, V_{EB(off)} = 3.0 \text{ V}$		10	nA
I <sub>CBO</sub>	Collector Cut-Off Current	$V_{CB} = 60 \text{ V}, I_{E} = 0$		0.01	μΑ
		$V_{CB} = 60 \text{ V}, \text{ I}_{E} = 0, \text{ T}_{A} = 125^{\circ}\text{C}$		10	
I <sub>EBO</sub>	Emitter Cut-Off Current	$V_{EB} = 3.0 \text{ V}, I_{C} = 0$		10	nA
I <sub>BL</sub>	Base Cut-Off Current	$V_{CE}$ = 60 V, $V_{EB(off)}$ = 3.0 V		20	nA
On Charact	eristics				
		$I_{C} = 0.1 \text{ mA}, V_{CE} = 10 \text{ V}$	35		
		$I_{C} = 1.0 \text{ mA}, V_{CE} = 10 \text{ V}$	50		]
		$I_{C} = 10 \text{ mA}, V_{CE} = 10 \text{ V}$	75		
h <sub>FE</sub>	DC Current Gain	$I_{C} = 10 \text{ mA}, V_{CE} = 10 \text{ V}, T_{A} = -55^{\circ}\text{C}$	35		
		$I_{\rm C}$ = 150 mA, $V_{\rm CE}$ = 10 V <sup>(4)</sup>	100	300	1
		I <sub>C</sub> = 150 mA, V <sub>CE</sub> = 1 V <sup>(4)</sup>	50		1
		$I_{\rm C}$ = 500 mA, $V_{\rm CE}$ = 10 V <sup>(4)</sup>	40		
M	Collector-Emitter Saturation Voltage <sup>(4)</sup>	I <sub>C</sub> = 150 mA, I <sub>B</sub> = 15 mA		0.3	v
V <sub>CE(sat)</sub>		$I_{\rm C} = 500 \text{ mA}, I_{\rm B} = 50 \text{ mA}$		1.0	V V
V	Base-Emitter Saturation Voltage <sup>(4)</sup>	I <sub>C</sub> = 150 mA, I <sub>B</sub> = 15 mA	0.6	1.2	V
V <sub>BE(sat)</sub>	Base Emilier Galaration Voltage	$I_{\rm C} = 500 \text{ mA}, I_{\rm B} = 50 \text{ mA}$		2.0	
Small Signa	al Characteristics				
f <sub>T</sub>	Current Gain Bandwidth Product	I <sub>C</sub> = 20 mA, V <sub>CE</sub> = 20 V, f = 100 MHz	300		МН
C <sub>obo</sub>	Output Capacitance	V <sub>CB</sub> = 10 V, I <sub>E</sub> = 0, f = 1 MHz		8.0	pF
C <sub>ibo</sub>	Input Capacitance	$V_{EB} = 0.5 V$ , $I_{C} = 0$ , f = 1 MHz		25	pF
rb'C <sub>c</sub>	Collector Base Time Constant	I <sub>C</sub> = 20 mA, V <sub>CB</sub> = 20 V, f = 31.8 MHz		150	pS
NF	Noise Figure	$I_{C}$ = 100 μA, V <sub>CE</sub> = 10 V, R <sub>S</sub> = 1.0 kΩ, f = 1.0 kHz		4.0	dB
Re(h <sub>ie</sub> )	Real Part of Common-Emitter High Frequency Input Impedance	I <sub>C</sub> = 20 mA, V <sub>CE</sub> = 20 V, f = 300 MHz		60	Ω
Switching C	Characteristics				
t <sub>d</sub>	Delay Time	V <sub>CC</sub> = 30 V, V <sub>EB(off)</sub> = 0.5 V,		10	ns
t <sub>r</sub>	Rise Time	$I_{\rm C} = 150 \text{ mA}, I_{\rm B1} = 15 \text{ mA}$		25	ns
t <sub>s</sub>	Storage Time	V <sub>CC</sub> = 30 V, I <sub>C</sub> = 150 mA,		225	ns
t <sub>f</sub>	Fall Time	$I_{B1} = I_{B2} = 15 \text{ mA}$		60	ns

## Note:

4. Pulse test: pulse width  $\leq 300~\mu s,$  duty cycle  $\leq 2.0\%.$ 



For current tape and reel specifications, visit Fairchild Semiconductor's online packaging area: <u>http://www.fairchildsemi.com/packing\_dwg/PKG-ZA03D\_BK.pdf</u>.



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